

1. DESCRIPTION

The XD/XL3526 is a high performance pulse width modulator integrated circuit intended for fixed frequency switching regulators and other power control applications.

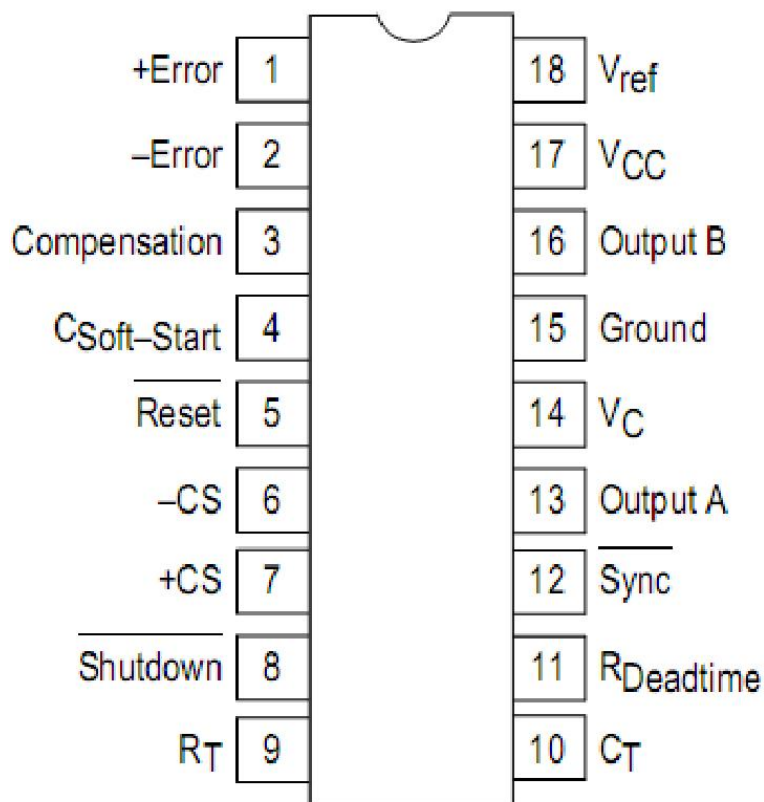
Functions included in this IC are a temperature compensated voltage reference,sawtooth oscillator,error amplifier, pulse width modulator, pulse metering and steering logic,and two high current totem pole outputs ideally suited for driving the capacitance of power FETs at high speeds.

Additional protective features include soft start and undervoltage lockout,digital current limiting,double pulse inhibit,adjustable dead time and a data latch for single pulse metering;. All digital control ports are TTL and B-series CMOS compatible. Active low logic design allows easy wired-OR connections for maximum flexibility.The versatility of this device enables implementation or transformer coupled.

2. FEATURES

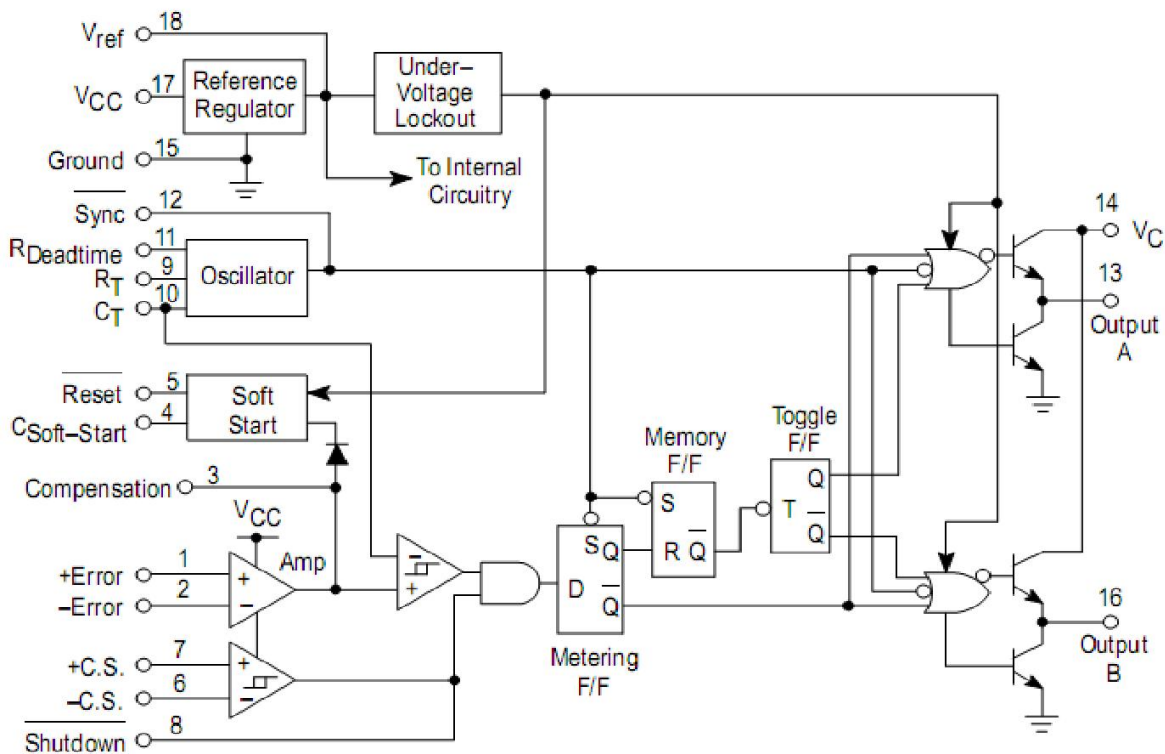
- 8.0V to 35V Operation
- 5.0V $\pm 1\%$ Trimmed Reference
- 1.0Hz to 400KHz Oscillator Range
- Dual Source/Sink Current Outputs:
 $\pm 100\text{mA}$
- Digital Current Limiting
- Programmable Dead Time
- Undervolage-Lockout
- Single Pulse Metering
- Programmable Soft-Start
- Wide Current Limit Common Mode Range
- Guaranteed 6 Unit Synchronization

3. PIN CONNECTIONS



(Top View)

4. REPRESENTATIVE BLOCK DIAGRAM



5. MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage	Vcc	+40	Vdc
Collector Supply Voltage	Vc	+40	Vdc
Logic Inputs		-0.3 to + 5.5	V
Analog Inputs		-0.3 to +5.5	V
Output Current,Source or Sink	Io	±200	mA
Reference Load Current(Vcc=40V Note2)	Iref	50	mA
Logic Sink Current		15	mA
Power Dissipation Ta=+25℃ (note3)	Pd	1000	mW
Operating Temperature Range	Ta	0~70	℃
Storage Temperature Range	Tstg	-65 to +150	℃
Lead Temperature(Soldering, 10Seconds)	Tsolder	±300	℃

NOTES:

1. Values beyond which damage may occur.
2. Maximum junction temperature must be observed.
3. Derate at 10 mW/℃ for ambient temperatures above +50℃.

6. RECOMMENDED OPERATING CONDITIONS

Charachteristics	Symbol	Min	Max	Unit
Supply Voltage	Vcc	8.0	35	Vdc
Collector Supply Voltage	Vc	4.5	35	Vdc
Output Sink/Source Current(Each Output)	Io	0	±100	mA
Reference Load Current	Iref	0	20	mA
Oscilliator Frequency Range	Fosc	0.0 01	400	Khz
Oscillator Timing Resistor	Rt	2.0	150	KΩ
Osicllator Timing Capacitor	Ct	0.0 01	20	uF
Available Deadtime Range(40Khz)	-	3.0	50	%
Operating Junction Temperature Range	Tj	0	+125	℃

7. ELECTRICAL CHARACTERISTICS

(VCC = +15 Vdc, TJ = Tlow to Thigh [Note 4], unless otherwise noted.)

Characteristics	Symbol	Min	Typ	Max	Unit
Reference Section					
Reference Output Voltage(Tj=+25℃)	Vref	4.90	5.00	5.10	V
Line Regulation(+8.0V ≤Vcc≤+35V)	Regline	-	10	30	mV
Load Regulation (0mA≤IL≤20mA)	Regload	-	10	50	mV
Short Circuit Current(Verf=0V)	Isc	25	80	125	mA
Undervoltage Lockout					
Reset Output Voltage(Vref=+3.8V)		-	0.2	0.4	V
Reset Output Voltage(Vref=+4.8V)		2.4	4.8	-	V
Oscillator Section(Note5)					
Initial Accuracy(Tj=+25℃)		-	±3.0	±8.0	%
Frequency Stability over Power Supply Range (+8.0V ≤Vcc≤+35V)	Δfosc/ Δ VCC	-	0.5	1.0	%
Minimun Frequency (Rt=150Kohm,Ct=20uF)	Fmin	-	0.5	-	Hz
Maximum Frequency (Rt=2.0Kohm,Ct=0.001uF)	Fmax	400	-	-	KHz
Sawtooth Peak Voltage (Vcc=35V)	Vosc(p)	-	3.0	3.5	V

Sawtooth Valley Voltage($V_{cc}=8.0V$)	$V_{osc}(V)$	0.45	0.8	-	V
Error Amplifier Section (note6)					
Input Offset Voltage	V_{io}	-	2.0	10	mV

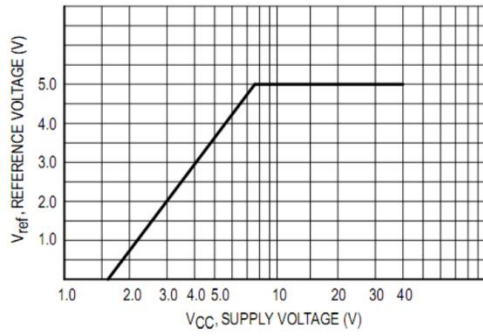
Input Bias Current	lib	-	-350	- 200 0	nA
Input Offset Current	lio	-	35	200	nA
Characteristics	Symbol	Min	Typ	Max	Unit
DC Open Loop Gain($R_l \geq 10M\Omega$)	A_v	60	72	-	dB
High Output Voltage ($V_{pin1}-V_{pin2} \geq +150mV$, $I_{source}=100\mu A$)	V_{oh}	3.6	4.2	-	V
Low Output Voltage ($V_{pin2}-V_{pin1} \geq +150mV$, $I_{sink}=100\mu A$)	V_{ol}	-	0.2	0.4	V
Common Mode Rejection Ratio($R_s \leq 2.0K\Omega$)	CMRR	70	94	-	dB
Power Supply Rejection Ration($+12V \leq V_{cc} \leq +18V$)	PSRR	66	80	-	dB
PWM Comparator Section(Note5)					
Minimum Duty Cycle ($V_{compensation} = +0.4V$)	D_{cmin}	-	-	0	%
Maximum Duty Cycle ($V_{compensation} = +3.6V$)	D_{cmax}	45	49	-	%
Digital Ports(SYNC,SHUTDOWN,RESET)					
Output Voltage (High Logic Level) ($I_{source}=40\mu A$) (Low Logic Level) ($I_{sink}=3.6mA$)	V_{oh} V_{ol}	2.4 -	4.0 0.2	- 0.4	V
Input Current-High Logic Level (High Logic Level) ($V_{ih}=+2.4V$) (Low Logic Level) ($V_{il} = +0.4V$)	I_{ih} I_{il}	- -	-125 -225	-200 -360	μA
Current Limit Comparator Section(note7)					
Sense Voltage($R_s \leq 50\Omega$)	V_{sense}	80	100	120	mA
Input Bias Current	lib	-	-3.0	-10	μA
Soft-Start Section					
Error Clamp Voltage(Reset= $+0.4V$)		-	0.1	0.4	V
Csoft-Start Charging Current(Reset= $+2.4V$)	I_{cs}	50	100	150	μA
Output Drivers (each output, $V_c=+15V_{dc}$) Unless otherwise noted.					
Output High Level $I_{source} = 20mA$ $I_{source} = 100mA$	V_{oh}	12.5 12	13.5 13	- -	V

Output Low Level Isink = 20 mA Isink = 100mA	Vol	-	0.2 1.2	0.3 2.0	V
Collector Leakage,Vc=+40V	Ic(Leak)	-	50	150	uA
Rise Time(CL=1000pF)	Tr	-	0.3	0.6	uS

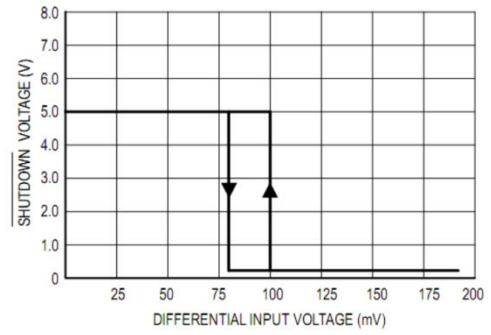
Fall Time (CL=1000pF)	Tf	-	0.1	0.2	uS
Supply Current (Shutdown = +0.4V, Vcc=+35V, Rt=4.12K Ω)	Icc	-	18	30	mA

Notes:

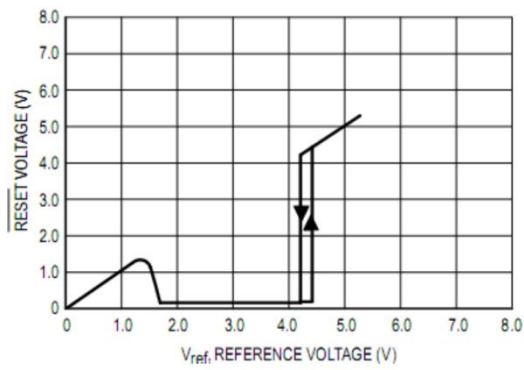
4. Tlow = 0°CThigh = +125°C
5. fosc=40KHz (Rt=4.12k Ω ±1%,CT=0.01uF±1%, RD=0 Ω)
6. 0V ≤ VCM ≤ +5.2V
7. 0V ≤ VCM ≤ +12V



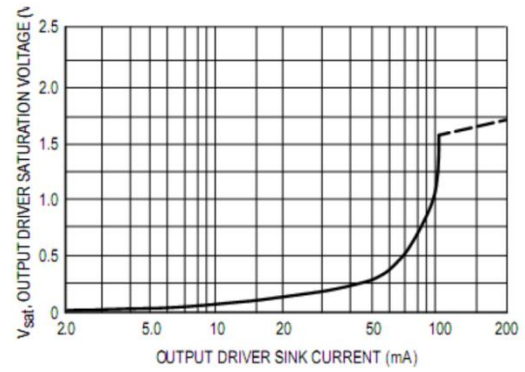
Reference Voltage as a Function Supply Votage



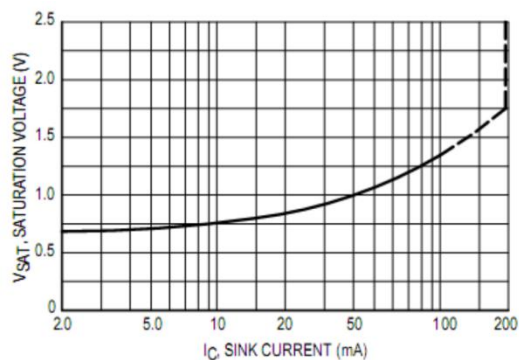
Current Limit Comparator Threshold



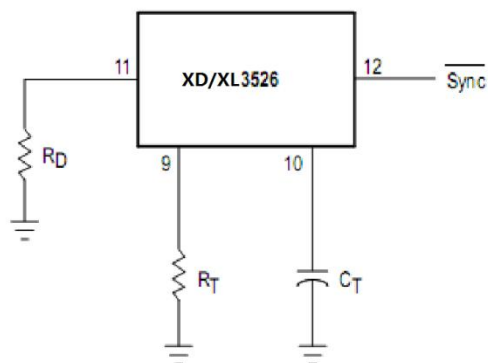
UnderVoltage Lockout Characteristic



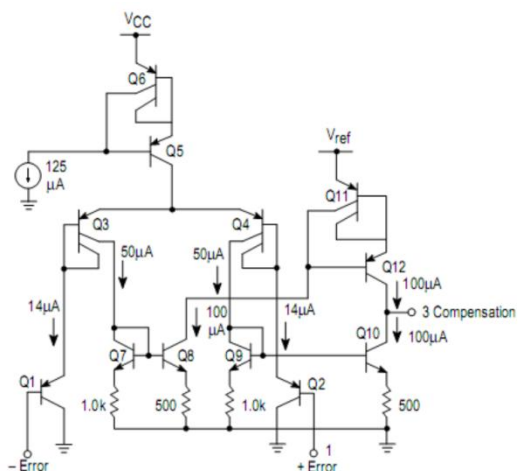
Output Driver Saturation Voltage as a Function of Sink Current



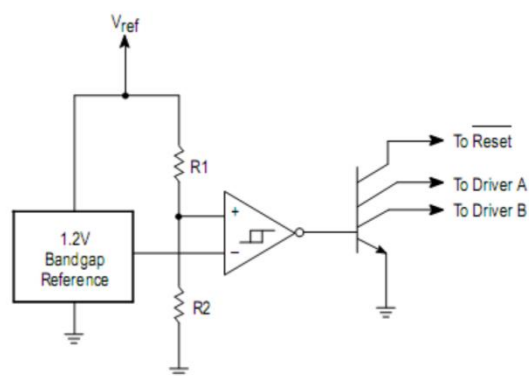
Vc Saturation Voltage as a Function of Sink Current



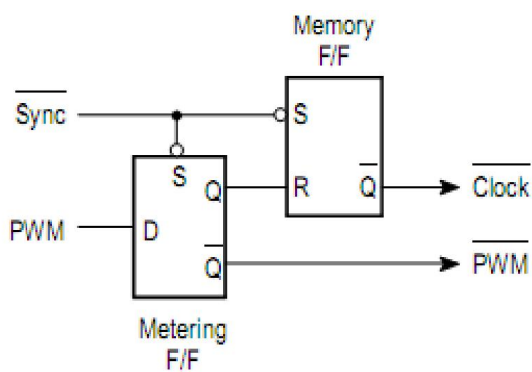
Oscillator Connections



Error Amplifier



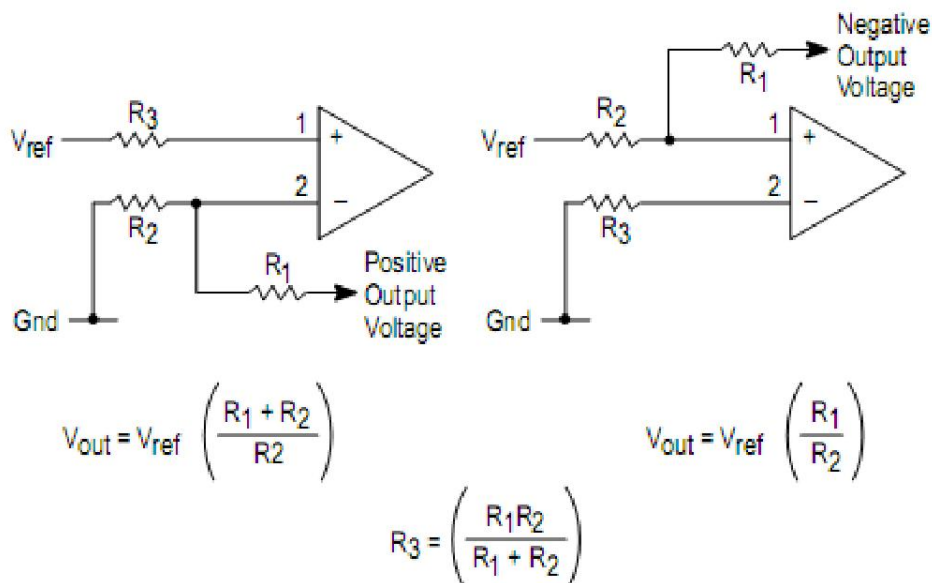
Undervoltage Lockout



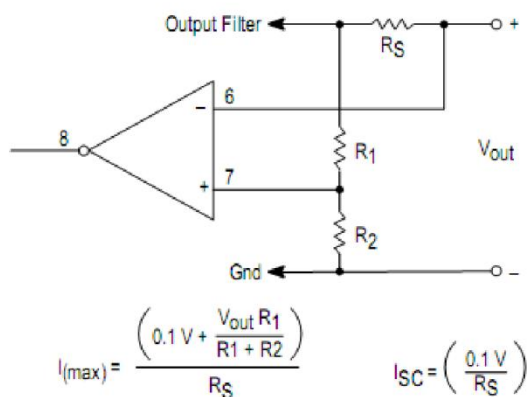
Pulse Processing Logic

The metering Flip-Flop is an asynchronous data latch which suppresses high frequency oscillations by allowing only one PWM pulse per oscillator cycle.

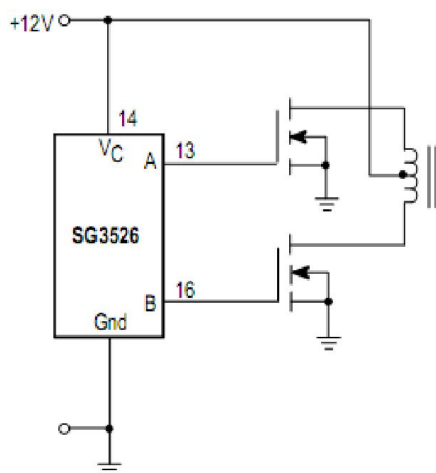
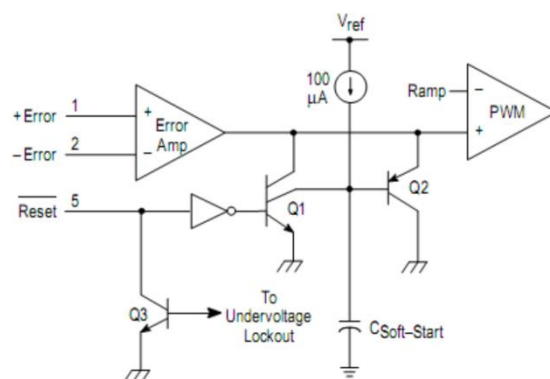
The memory Flip-Flop prevents double pulsing in a push-pull configuration by remembering which output produced the last pulse.



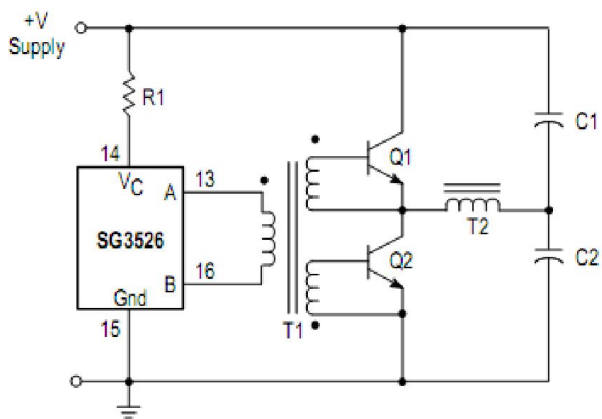
Error Amplifier Connects



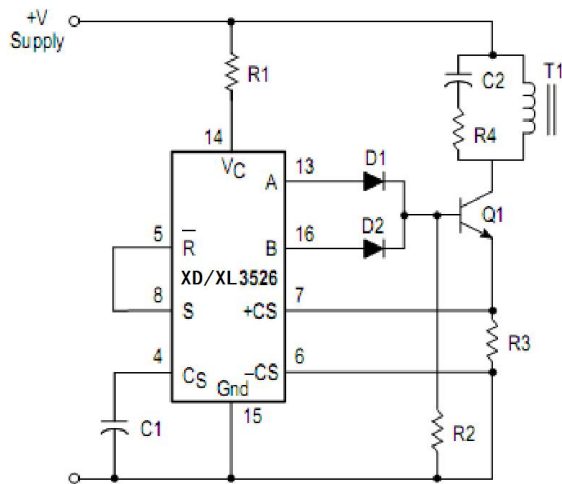
Foldback Current Limiting



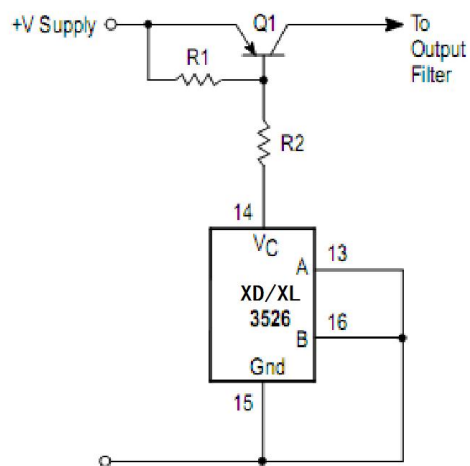
Driving VMOS Power FETs



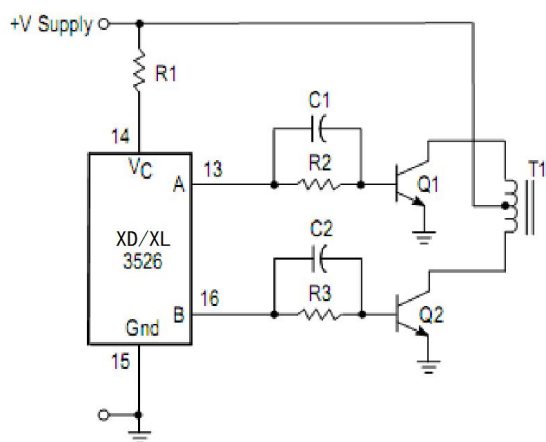
Half-Bridge Configuration



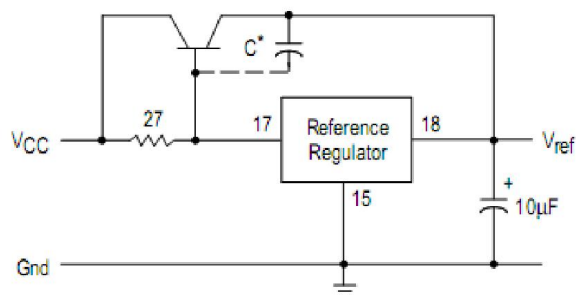
Flyback Converter with Current Limiting



Single-Ended Configuration



Push-Pull Configuration



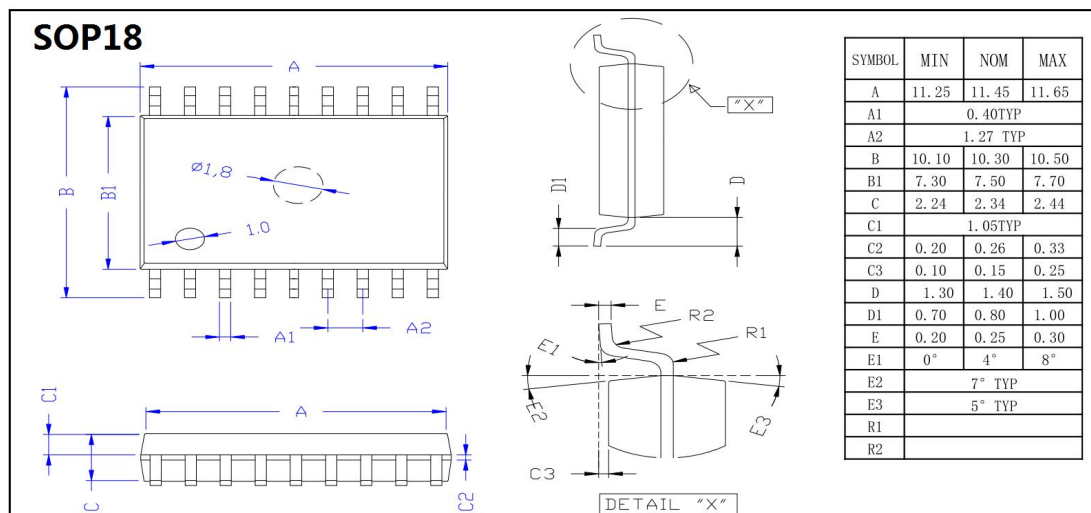
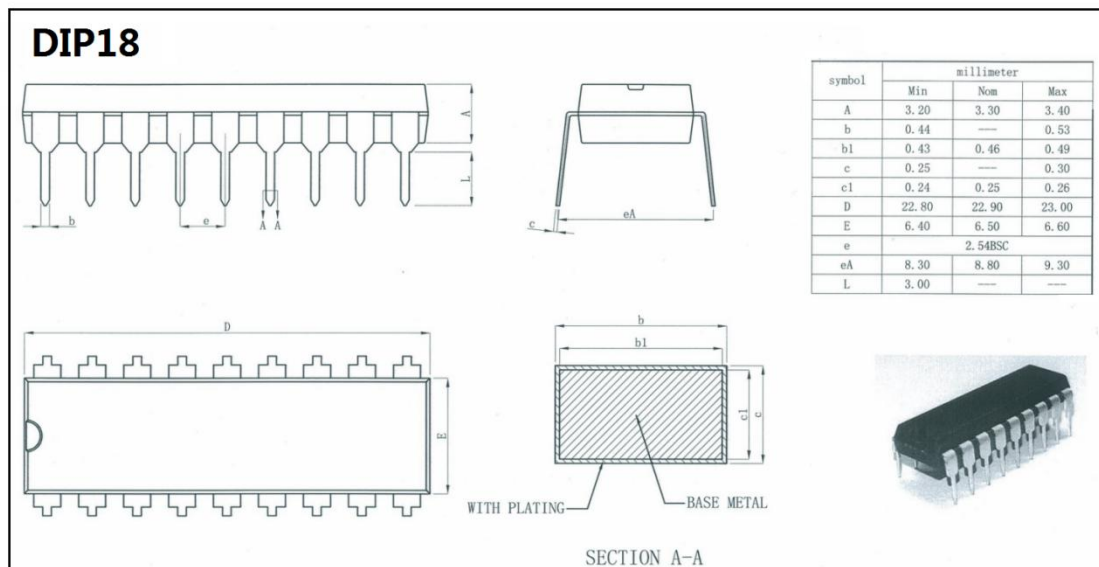
Extending Reference Output Current Capability

8. ORDERING INFORMATION

Ordering Information

Part Number	Device Marking	Package Type	Body size (mm)	Temperature (°C)	MSL	Transport Media	Package Quantity
XD3526	XD3526	DIP18	22.90*6.50	-0 to +70	MSL3	Tube 20	1000
XL3526	XL3526	SOP18	11.45*7.50	-0 to +70	MSL3	T&R	1000

9. DIMENSIONAL DRAWINGS



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